



SANYO Semiconductors

DATA SHEET

LA6581M — Monolithic Linear IC Fan Motor Driver BTL Driver Single-Phase Full-Wave

Overview

The LA6581M is single-phase bipolar fan motor is driven, through BTL output linear drive, at high efficiency, low power, and low sound by suppressing the reactive power. Lock protection, rotary signal (FG, RD) circuits are incorporated, which is optimum for the notebook PC, consumer equipment power supply, car audio system, CPU cooler, etc. that require high reliability and low noise.

Features

- Single-phase full-wave linear drive for fan motor

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V_{CC} max		18	V
OUT output current	I_{OUT} max	$T < 200\text{ms}$	0.50	A
OUT output withstand voltage	V_{OUT} max		18	V
FG output withstand	V_{FG} max		18	V
FG output current	I_{FG} max		5	mA
Allowable dissipation	P_d max	Mounted on a specified board *1	800	mW
Operating temperature	T_{opr}	*2	-30 to +100	$^\circ\text{C}$
Storage temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

*1: Mounted on a specified board: 114.3mm×76.1mm×1.6mm glass epoxy

*2: $T_j = 150^\circ\text{C}$ max must not be exceeded.

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SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

32807 TI IM B8-8743 No.8774-1/4

LA6581M

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	V _{CC}		2.2 to 16	V
Common-phase input voltage range of Hall input	V _{ICM}		0.3 to V _{CC} -1.5	V

Electrical Characteristics at Ta = 25°C, V_{CC} = 12.0V, unless especially specified.

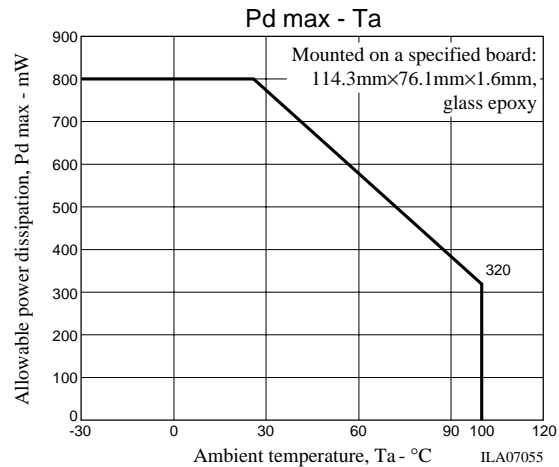
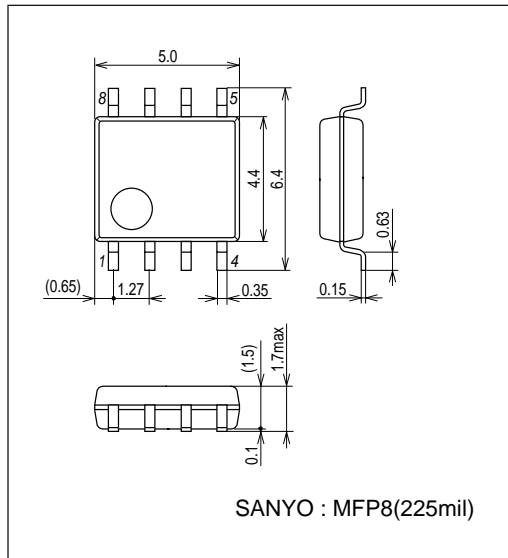
Parameter	Symbol	Conditions	Ratings			Unit
			min	Typ	Max	
Circuit Current	I _{CC}	IN=-5.8V, IN+=6.0V, R _L =∞		14	19	mA
OUT output low voltage	V _{OL}	I _O =100mA		0.1	0.2	V
OUT output high voltage	V _{OH}	I _O =100mA		0.1	0.2	V
Hall bias voltage	V _{HB}	RH=360Ω +91Ω	1.85	1.95	2.05	V
Hall amplifier gain	V _g		52	55	58	dB
Hall amplifier input current	V _{INR}		-10	-2	10	μA
FG output low voltage	V _{FG}	IFG=3mA		0.2	0.3	V
FG output leakage current	IFGL	VFG=7V			30	μA
Thermal protection circuit	Th	* Design guarantee	150	180	200	°C

*: These values are design guarantee values, and are not tested.

Package Dimensions

unit : mm (typ)

3032D

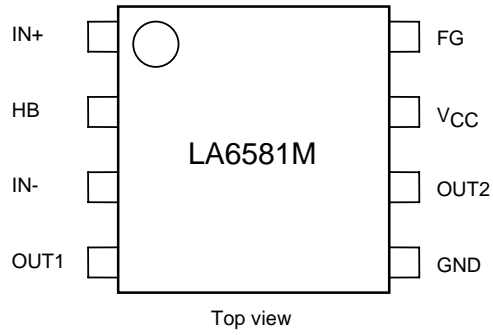


Truth Table

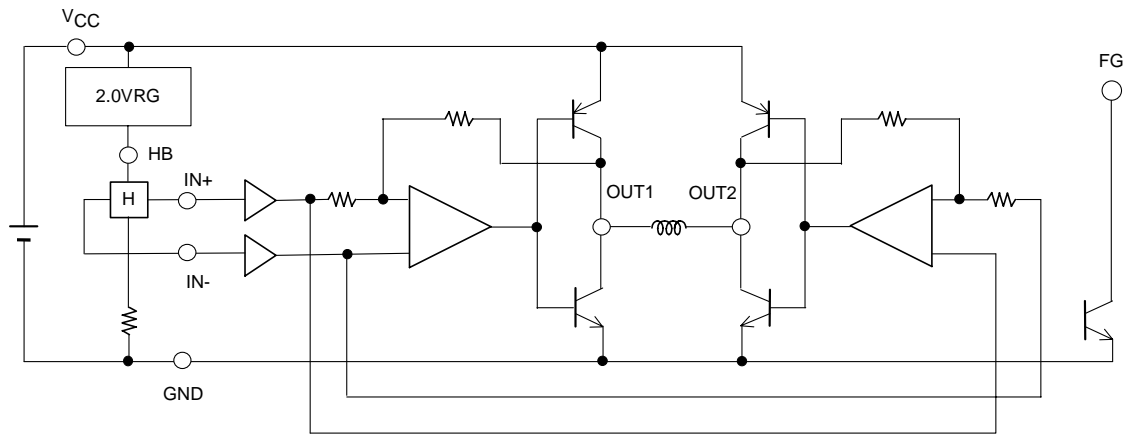
IN-	IN+	OUT1	OUT2	FG	mode
H	L	H	L	L	During rotation
L	H	L	H	Off	
-	-	Off	Off	-	During overheat protection

LA6581M

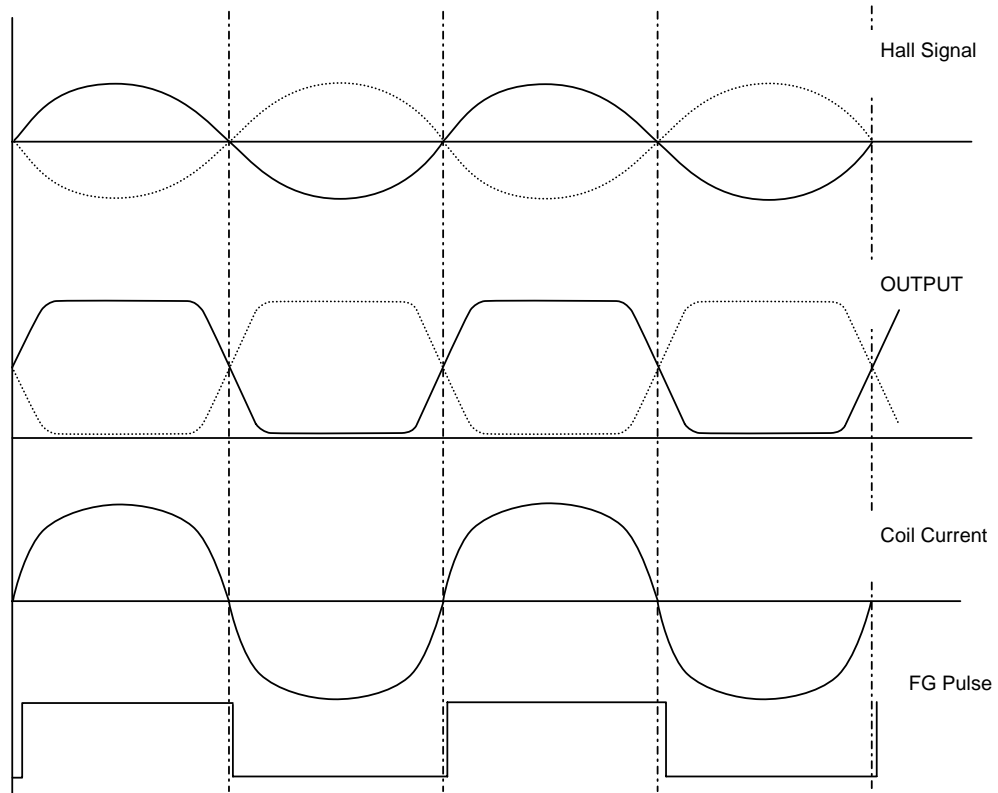
Pin Assignment



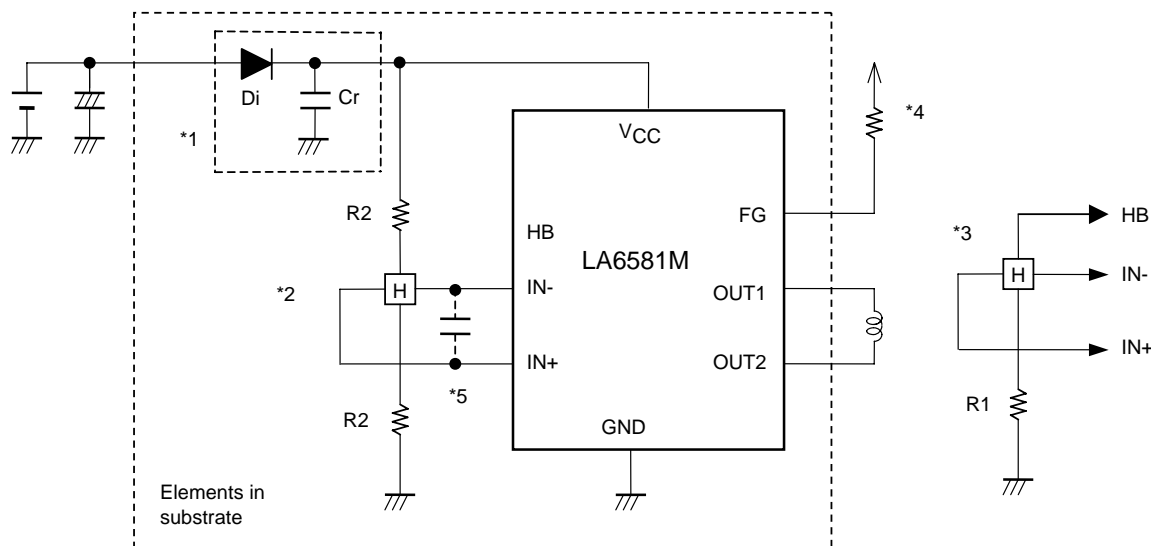
Block Diagram



Timing Chart



Sample Application Circuit



- *1: When Di to prevent breakdown in case of reverse connection is used, it is necessary to insert a capacitor Cr to secure the regenerative current route. Similarly, Cr is necessary to enhance the reliability when there is no capacitor near the fan power line.
- *2: To obtain Hall bias from VCC, carry out $1/2 \times V_{CC}$ bias as shown in the figure. Linear driving is made through voltage control of the coil by amplifying the Hall output. When the Hall element output is large, the startup performance and efficiency are improved. Adjustment of the Hall element can reduce the noise further.
- *3: When the Hall bias is taken from the HB pin, constant-voltage bias is made with about 2.0V. Therefore, the Hall element can provide the output satisfactory in temperature characteristics. Adjustment of the Hall output amplitude is made with R1. (When $V_{CC} = 12V$, the step *2 above proves advantageous for IC heat generation.)
- *4: Keep this open when not used.
- *5: When the wiring from the Hall output to IC Hall input is long, noise may be carried through the wiring. In this case, insert the capacitor as shown in the figure.

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